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BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC3221GV$

5 V AGC AMPLIFIER + VIDEO AMPLIFIER

DESCRIPTION

The μ PC3221GV is a silicon monolithic IC designed for use as AGC amplifier for digital CATV, cable modem systems. This IC consists of gain control amplifier and video amplifier.

The package is 8-pin SSOP suitable for surface mount.

This IC is manufactured using our 10 GHz f_T NESAT II AL silicon bipolar process. This process uses silicon nitride passivation film. This material can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

FEATURES

Low distortion
 : IM₃ = 56 dBc TYP. @ single-ended output, V_{out} = 0.7 V_{p-p}/tone

Low noise figure : NF = 4.2 dB TYP.

Wide AGC dynamic range : GCR = 50 dB TYP. @ input prescribe
 On-chip video amplifier : Vout = 1.0 Vp-p TYP. @ single-ended output

• Supply voltage : Vcc = 5.0 V TYP.

· Packaged in 8-pin SSOP suitable for surface mounting

APPLICATION

· Digital CATV/Cable modem receivers

ORDERING INFORMATION

Part Number	Package	Supplying Form
μPC3221GV-E1-A	8-pin plastic SSOP (4.45 mm (175))	 Embossed tape 8 mm wide Pin 1 indicates pull-out direction of tape Qty 1 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office.

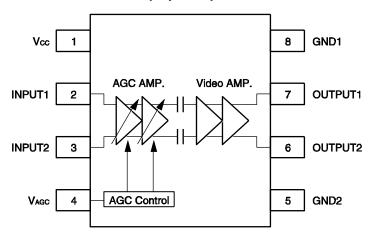
Part number for sample order: μPC3221GV-A

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

INTERNAL BLOCK DIAGRAM AND PIN CONNECTIONS

(Top View)



PRODUCT LINE-UP OF 5 V AGC AMPLIFIER

Part Number	Icc (mA)	Gмах (dB)	G _{MIN} (dB)	GCR (dB)	NF (dB)	IM ₃ (dBc) Note	Package
μPC3217GV	23	53	0	53	6.5	50	8-pin SSOP (4.45 mm (175))
μPC3218GV	23	63	10	53	3.5	50	
μPC3219GV	36.5	42.5	0	42.5	9.0	58	
μPC3221GV	33	60	10	50	4.2	56	

Note $f_1 = 44$ MHz, $f_2 = 45$ MHz, $V_{out} = 0.7$ $V_{p\text{-}p}/tone$, single-ended output

PIN EXPLANATIONS

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) ^{Note}	Function and Application	Internal Equivalent Circuit
1	Vcc	4.5 to 5.5	-	Power supply pin. This pin should be externally equipped with bypass capacitor to minimize ground impedance.	
2	INPUT1	-	1.29	Signal input pins to AGC amplifier. This pin should be coupled with capacitor for DC cut.	AGC Control
3	INPUT2	I	1.29		2 5 3
4	Vago	0 to Vcc	_	Gain control pin. This pin's bias govern the AGC output level. Minimum Gain at V _{AGC} : 0 to 0.5 V Maximum Gain at V _{AGC} : 3 to 3.5 V Recommended to use AGC voltage with externally resister (example: 1 k Ω).	AGC Amp.
5	GND2	0	-	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible.	
6	OUTPUT2	_	2.28	Signal output pins of video amplifier. This pin should be coupled with capacitor for DC cut.	7)
7	OUTPUT1	_	2.28		8
8	GND1	0	-	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All ground pins must be connected together with wide ground pattern to decrease impedance difference.	

Note Pin voltage is measured at Vcc = 5.0 V.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	Vcc	T _A = +25°C	6.0	V
Gain Control Voltage Range	Vagc	T _A = +25°C	0 to Vcc	V
Power Dissipation	Po	T _A = +85°C Note	250	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Note Mounted on double-sided copper-clad $50 \times 50 \times 1.6$ mm epoxy glass PWB

RECOMMENDED OPERATING RANGE

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc		4.5	5.0	5.5	V
Operating Ambient Temperature	TA	Vcc = 4.5 to 5.5 V	-40	+25	+85	°C
Gain Control Voltage Range	Vagc		0	-	3.5	V
Operating Frequency Range	fвw		10	45	100	MHz

ELECTRICAL CHARACTERISTICS

(TA = +25°C, Vcc = 5 V, f = 45 MHz, Zs = 50 Ω , ZL = 250 Ω , single-ended output)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Circuit Current	Icc	No input signal Note 1	26	33	41	mA
AGC Pin Current	IAGC	No input signal, Vagc = 3.5 V Note 1	_	16	50	μΑ
AGC Voltage High Level	VAGC (H)	@ Maximum gain Note 1	3.0	_	3.5	٧
AGC Voltage Low Level	Vagc (L)	@ Minimum gain Note 1	0	_	0.5	٧
RF Characteristics						
Maximum Voltage Gain	Gмах	Vagc = 3.0 V, Pin = -60 dBm Note 1	57	60	63	dB
Middle Voltage Gain 1	Gмід1	V _{AGC} = 2.2 V, P _{in} = -60 dBm Note 1	47.5	50.5	53.5	dB
Middle Voltage Gain 2	Gмід2	Vagc = 1.2 V, Pin = -30 dBm Note 1	18	21	24	dB
Minimum Voltage Gain	Gмin	Vagc = 0.5 V, Pin = -30 dBm Note 1	6	10	14	dB
Gain Control Range (input prescribe)	GCRin	Vagc = 0.5 to 3.0 V Note 1	43	50	-	dB
Gain Control Range (output prescribe)	GCRout	Vout = 1.0 V _{p-p} Note 1	36	40	-	dB
Gain Slope	Gslope	Gain (@ Vagc = 2.2 V) - Gain (@ Vagc = 1.2 V) Note 1	26.5	29.5	32.5	dB/V
Maximum Output Voltage	Voclip	Vagc = 3.0 V (@ Maximum gain) Note 1	2.0	2.8	-	V _{p-p}
Noise Figure	NF	Vagc = 3.0 V (@ Maximum gain) Note 3	-	4.2	5.7	dB
3rd Order Intermodulation Distortion 1	IM₃1	$\begin{split} &\text{f}_1=44\text{ MHz, f}_2=45\text{ MHz, ZL}=250\ \Omega,\\ &\text{P}_{\text{in}}=-30\text{ dBm/tone,}\\ &\text{V}_{\text{out}}=0.7\text{ V}_{\text{P-P}}\text{/tone (@ single-ended}\\ &\text{output)} &\text{\textbf{Note 1}} \end{split}$	43	47	-	dBc
3rd Order Intermodulation Distortion 2	IM ₃ 2	$\begin{split} &\text{f}_1 = 44 \text{ MHz, f}_2 = 45 \text{ MHz, ZL} = 250 \ \Omega, \\ &\text{V}_{\text{AGC}} = 3.0 \text{ V (@ Maximum gain),} \\ &\text{V}_{\text{out}} = 0.7 \text{ V}_{\text{P-P}}/\text{tone (@ single-ended} \\ &\text{output)} \end{split}$	50	56	-	dBc
Gain Difference of OUTPUT1 and OUTPUT2	⊿G	$V_{AGC} = 3.0 \; V, \; P_{in} = -60 \; dBm, \\ \varDelta G = G \; (@ \; P_{out} 1) - G \; (@ \; P_{out} 2) \\ \textbf{Note 1, 2}$	-0.5	0	+0.5	dB

Notes 1. By measurement circuit 1

2. By measurement circuit 2

3. By measurement circuit 3

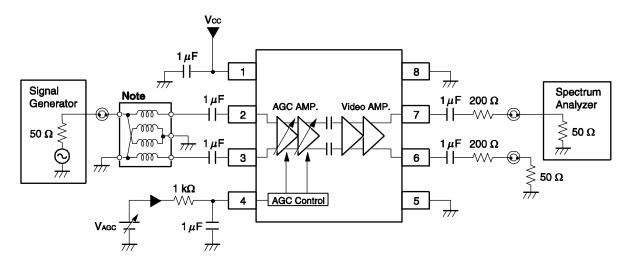
STANDARD CHARACTERISTICS (Ta = +25°C, Vcc = 5 V, Zs = 50 Ω)

Parameter	Symbol	Test Conditions	Reference Value	Unit
Noise Figure 2	NF2	Gain reduction = -10 dBm Note	6.0	dB
Noise Figure 3	NF3	Gain reduction = -20 dBm Note	9.5	dB
Output Voltage	Vout	$P_{in} = -56 \text{ to } -16 \text{ dBm}$ Note	I 1.0	V _{p-p}
Input Impedance	Zin	Vagc = 0.5 V, f = 45 MHz Note	0.9 k – j1.4 k	Ω
Output Impedance	Zout	Vagc = 0.5 V, f = 45 MHz Note	9.0 + j1.9	Ω
Input 3rd Order Distortion Intercept Point	IIP ₃	$V_{\text{AGC}} = 0.5 \text{ V (@ Minimum gain)},$ $f_1 = 44 \text{ MHz}, f_2 = 45 \text{ MHz},$ $Z_{\text{L}} = 250 \ \Omega \text{ (@ single-ended output)}$ Note	+2.5	dBm

Notes 1. By measurement circuit 1

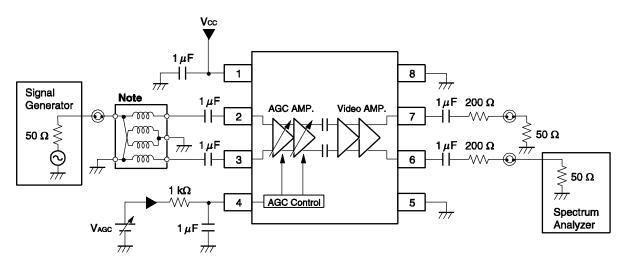
- 2. By measurement circuit 3
- 3. By measurement circuit 4

MEASUREMENT CIRCUIT 1



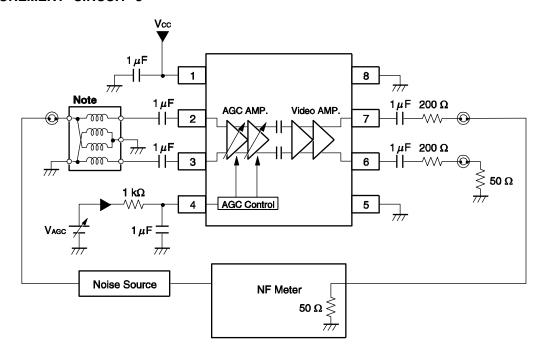
Note Balun Transformer: TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 2



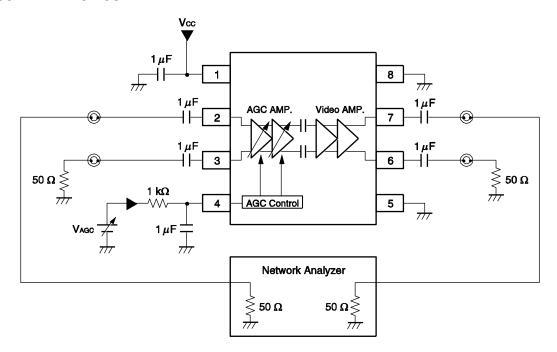
Note Balun Transformer: TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 3



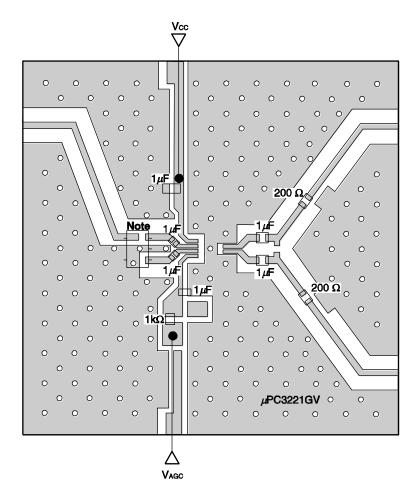
Note Balun Transformer: TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 4



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

■ ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD (MEASUREMENT CIRCUIT 1)



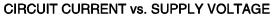
Note Balun Transformer

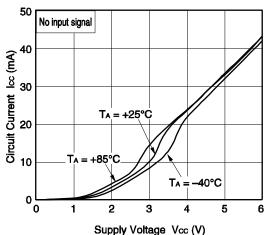
Remarks

Back side: GND pattern
 Solder plated on pattern

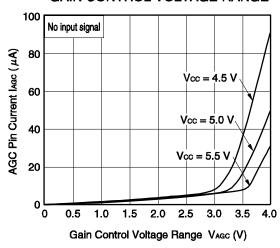
3. o: Through hole

■ TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

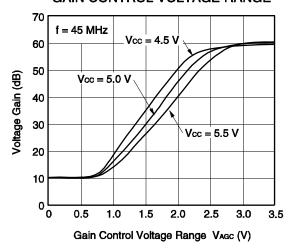




AGC PIN CURRENT vs.
GAIN CONTROL VOLTAGE RANGE

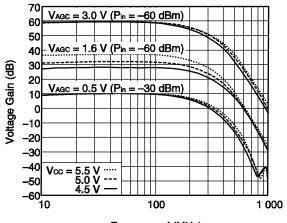


VOLTAGE GAIN vs.
GAIN CONTROL VOLTAGE RANGE



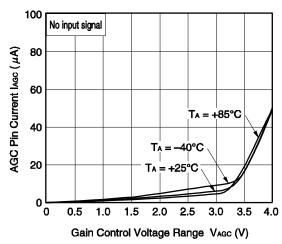
Remark The graphs indicate nominal characteristics.

VOLTAGE GAIN vs. FREQUENCY

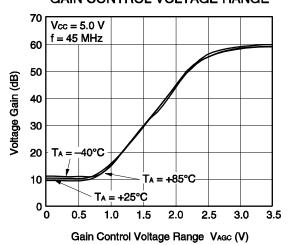


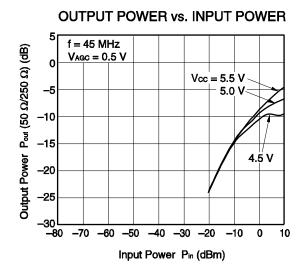
Frequency f (MHz)

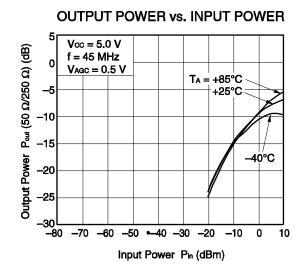
AGC PIN CURRENT vs. GAIN CONTROL VOLTAGE RANGE

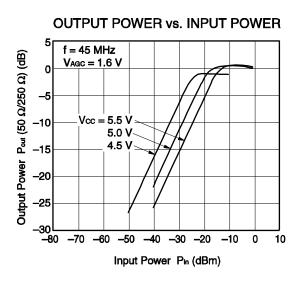


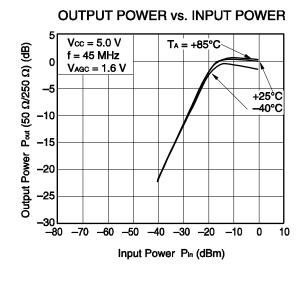
VOLTAGE GAIN vs.
GAIN CONTROL VOLTAGE RANGE

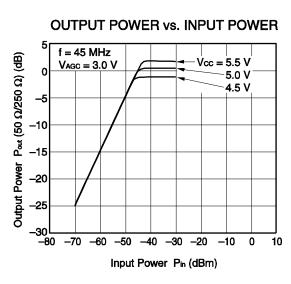


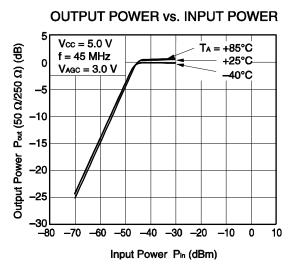




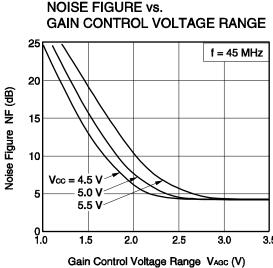




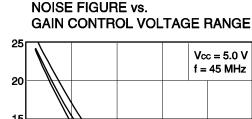


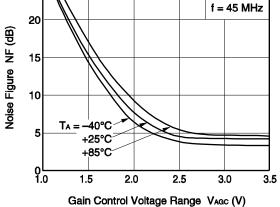


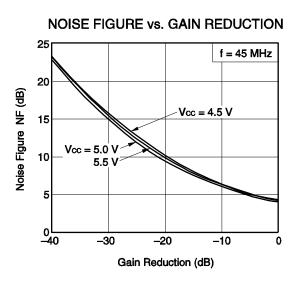
Remark The graphs indicate nominal characteristics.



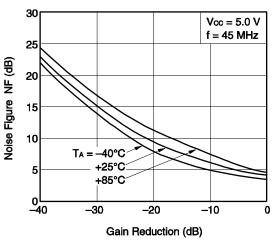


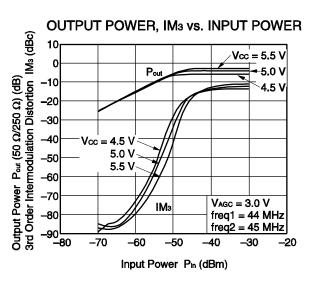


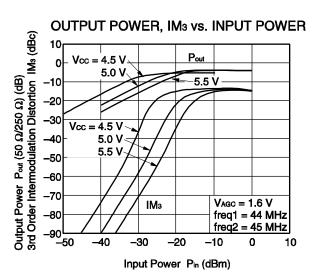




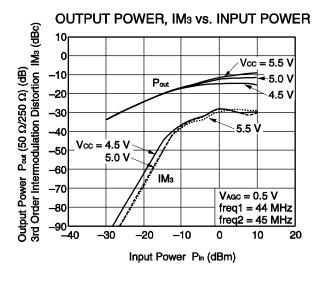


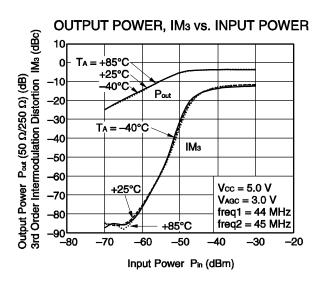


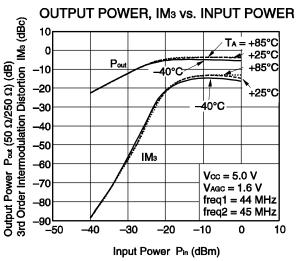


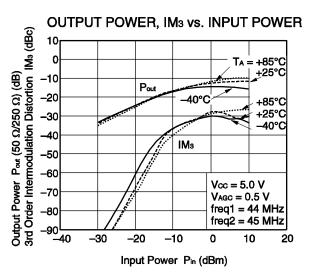


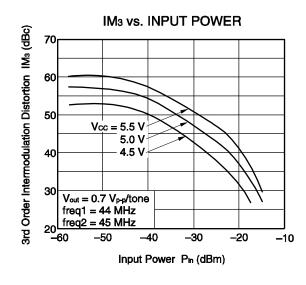
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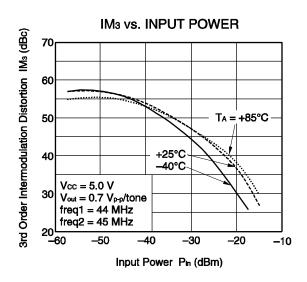








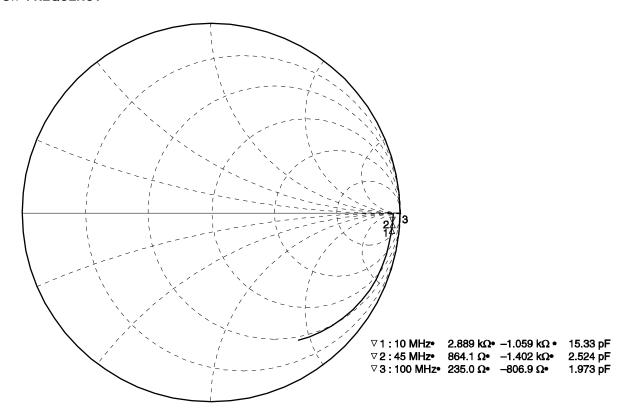




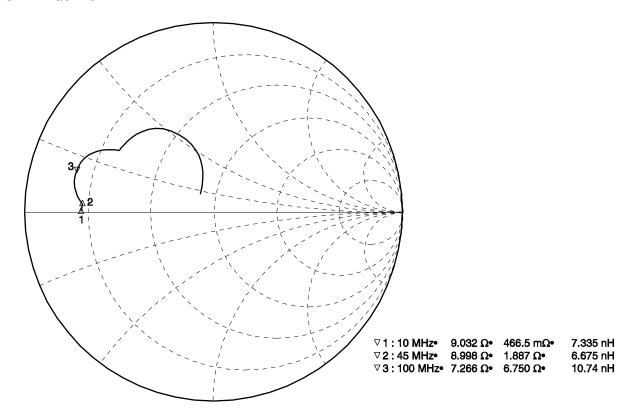
Remark The graphs indicate nominal characteristics.

S-PARAMETERS (TA = +25°C, Vcc = Vagc = 5.0 V)

S₁₁-FREQUENCY

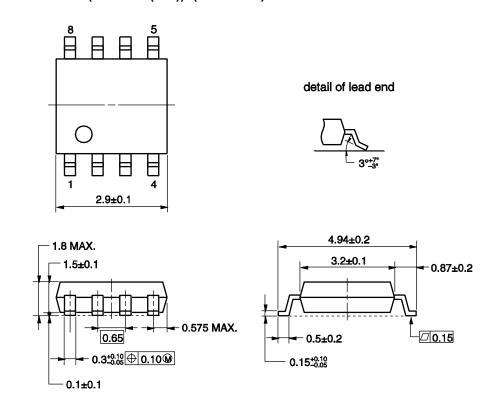


S22-FREQUENCY



PACKAGE DIMENSIONS

8-PIN PLASTIC SSOP (4.45 mm (175)) (UNIT: mm)



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
 - All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
VPS	Peak temperature (package surface temperature) Time at temperature of 200°C or higher Preheating time at 120 to 150°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 215°C or below : 25 to 40 seconds : 30 to 60 seconds : 3 times : 0.2%(Wt.) or below	VP215
Wave Soldering	Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 120°C or below : 1 time : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).